

Lecture 02132019

Sung Yeul Park

Department of Electrical & Computer Engineering

University of Connecticut

Email: sung_yeul.park@uconn.edu

simple \leftarrow RISC: reduced Instruction set computer

131

AVR

1 cycle
clock

1 instruction

LD: load value

CP: compare value

assembly language

C compiler

Assembly language
not shown

compile & link

asm is generated

link

executable code

flash memory

CISC: Complex Instruction set computer

15 x 16

= 240

intel

8051

2, 4 cycles for 1 instruction

crystal $\frac{1}{101}$
External Clock
source

20 MIPS
million
instructions
per second

Speed Grade.

0 - 4 MHz

0 - 10 MHz

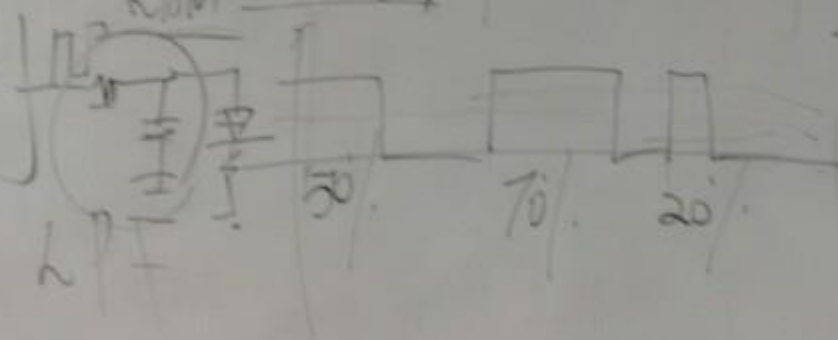
0 - 20 MHz

V_{CC} - GND

4.5 - 5.5V

{ flash } → can be erase and write 10,000 times 10 times →
7 months 3 yrs 100
 program memory - program will be downloaded
 - power is on, executing from the
 flash (one code).
 { data memory }

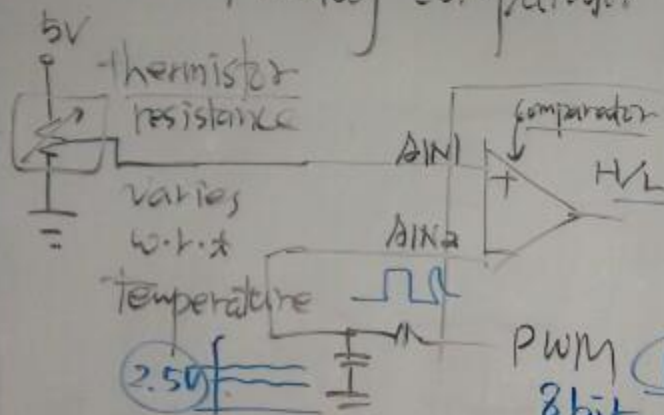
{ EEPROM : read only memory - power off, data is available
 read random memory
SRAM : RAM - power off, data is gone.



2^8 2^{16}
 $\frac{2^8}{2^{16}}$
 5 timer/counter.

PWM
 Pulse width modulation
 DAC

Analog comparator



temperature sensing value detect.



125 digit
25°C
45°F

32 T&FP package

